

# S2M024230BJ



TriQSiC™ 2300V Silicon Carbide Power MOSFET G2

## Features

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## Benefits

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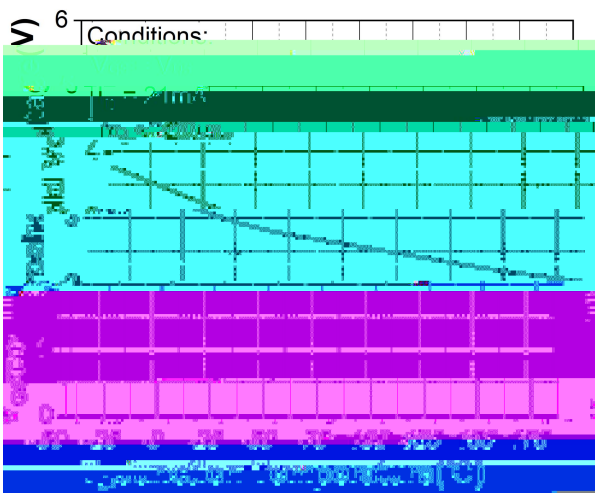
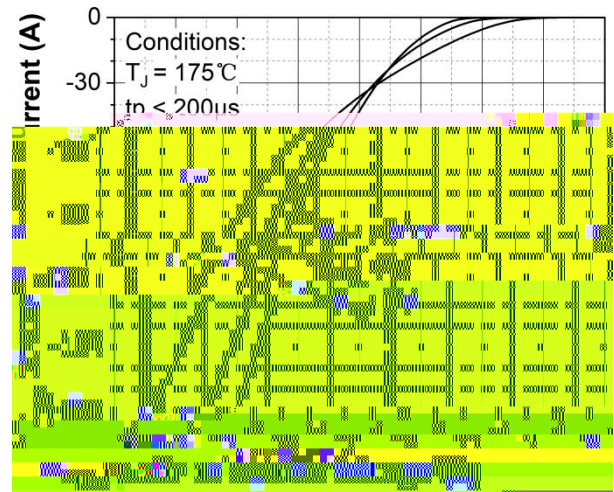
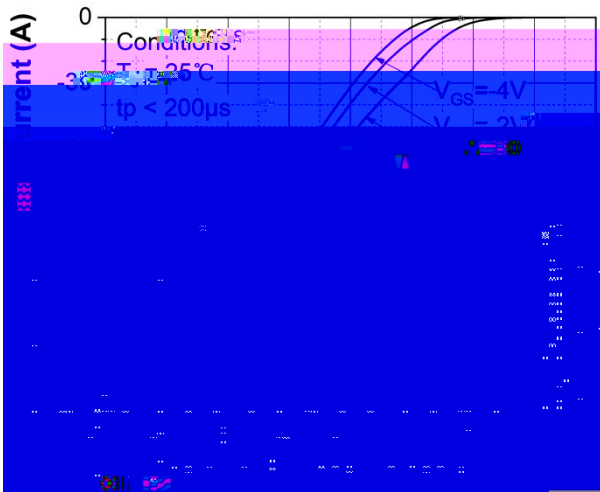
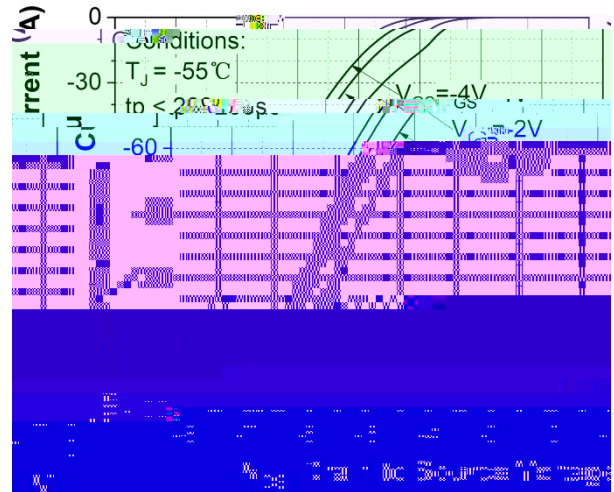
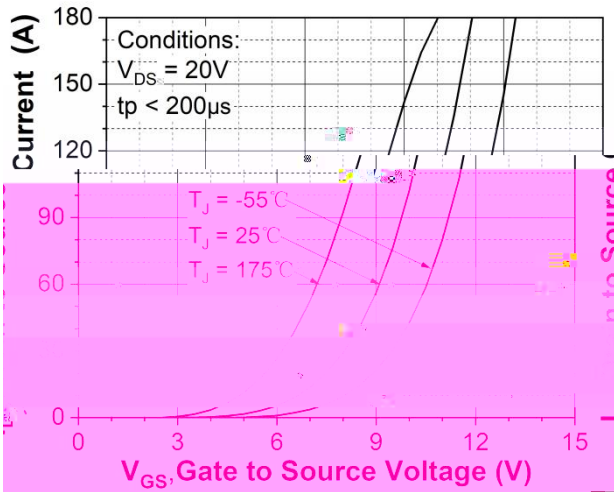
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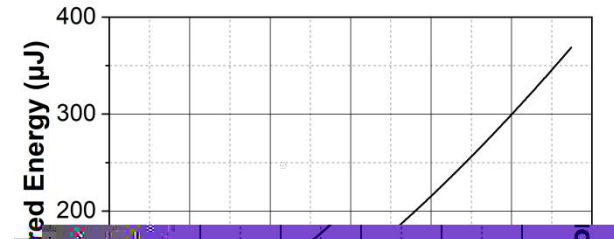
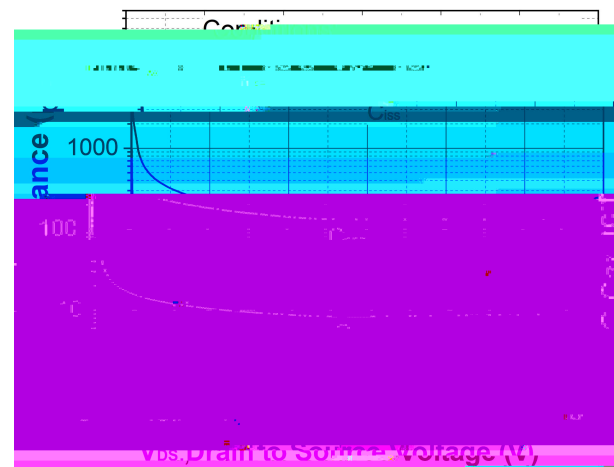
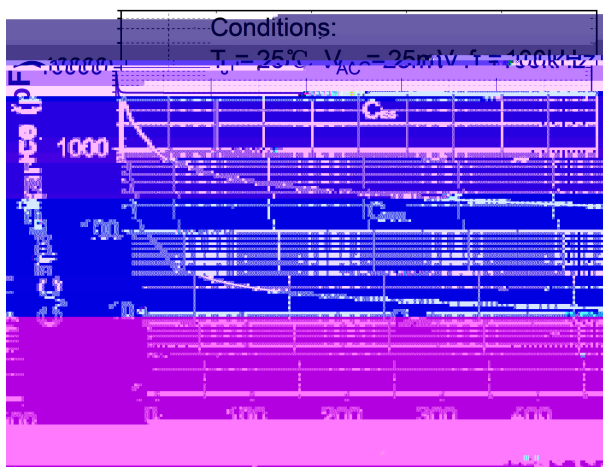
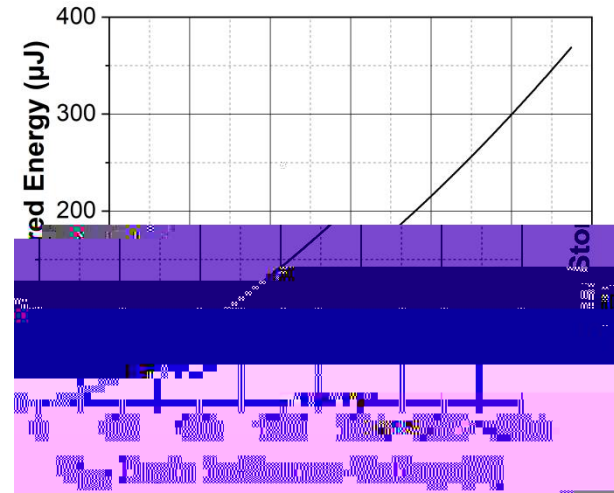
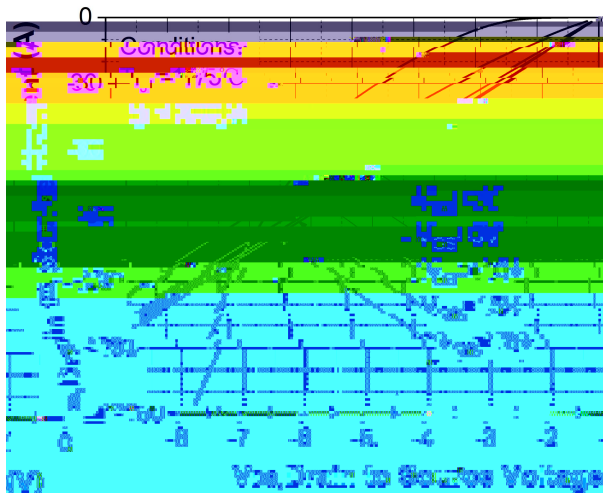
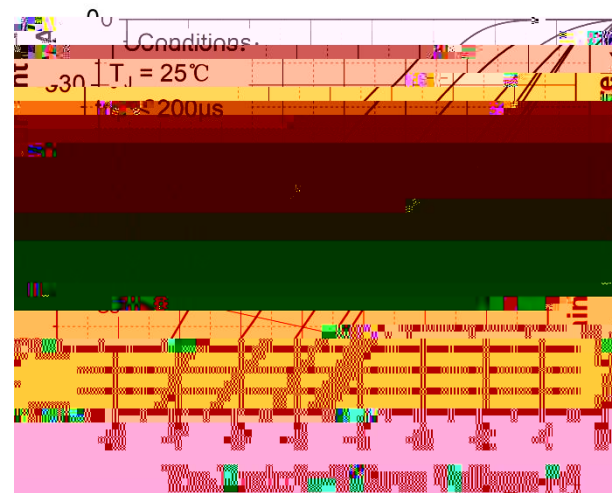
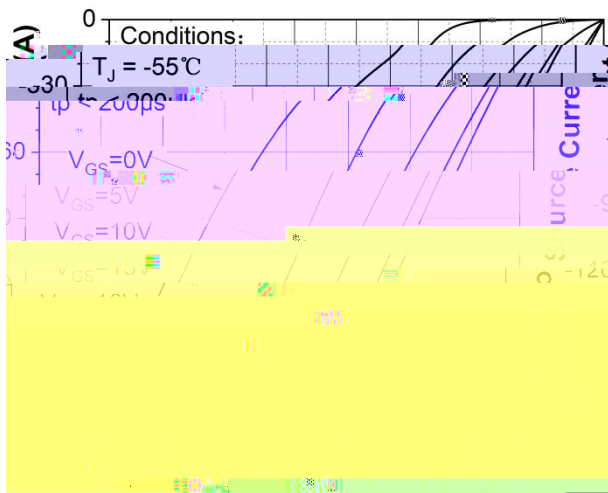

### 2.3 Switch



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### 4 Mechanical parameters

#### 4.1 Dimensions and metallization

Parameter	Typical value	Unit	Metallization
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## Revision history

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